

NCS2200, NCS2200A, NCV2200

Low Voltage Comparators

The NCS2200 Series is an industry first sub-one volt, low power comparator family. These devices consume only 10 μ A of supply current. They are guaranteed to operate at a low voltage of 0.85 V which allows them to be used in systems that require less than 1.0 V and are fully operational up to 6.0 V which makes them convenient for use in both 3.0 V and 5.0 V systems. Additional features include no output phase inversion with overdriven inputs, internal hysteresis, which allows for clean output switching, and rail-to-rail input and output performance. The NCS2200 Series is available in the tiny SOT-23-5 package. There are four options featuring two industry standard pinouts. Additionally, the NCS2200 and NCS2202 are available in the SC70-5 package. The NCS2200 is also available in the tiny DFN 2x2.2 package. The NCS2200A is available in UDFN 1.2x1.0 package. (Table 1)

Features

- Operating Voltage of 0.85 V to 6.0 V
- Rail-to-Rail Input/Output Performance
- Low Supply Current of 10 μ A
- No Phase Inversion with Overdriven Input Signals
- Glitchless Transitioning in or out of Tri-State Mode
- Complementary or Open Drain Output Configuration
- Internal Hysteresis
- Propagation Delay of 1.1 μ s
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

Typical Applications

- Single Cell NiCd/NiMH Battery Powered Applications
- Cellular Telephones
- Alarm and Security Systems
- Personal Digital Assistants

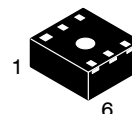


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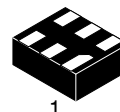
**SOT-23-5 (TSOP-5)
SN SUFFIX
CASE 483**



**DFN 2x2.2
SQL SUFFIX
CASE 488**



**SC70-5
SQ SUFFIX
CASE 419A**



**UDFN 1.2x1.0
MU SUFFIX
CASE 517AA**

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 12 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 13 of this data sheet.

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Table 1. Comparator Selector Guide

Output Type	Device	Package	Pinout Style
Complementary	NCS2200AMUT1G	UDFN, 1.2x1.0	N/A
Complementary	NCS2200SN1T1G	SOT-23-5	1
Complementary	NCV2200SN1T1G*	SOT-23-5	1
Complementary	NCS2200SN2T1G	SOT-23-5	2
Complementary	NCV2200SN2T1G*	SOT-23-5	2
Complementary	NCS2200SQ2T2G	SC70-5	2
Complementary	NCV2200SQ2T2G*	SC70-5	2
Complementary	NCS2200SQLT1G	DFN, 2x2.2	N/A
Open Drain	NCS2202SN1T1G	SOT-23-5	1
Open Drain	NCS2202SN2T1G	SOT-23-5	2
Open Drain	NCV2202SN2T1G*	SOT-23-5	2
Open Drain	NCS2202SQ1T2G	SC70-5	1
Open Drain	NCS2202SQ2T2G	SC70-5	2

*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

PIN CONNECTIONS

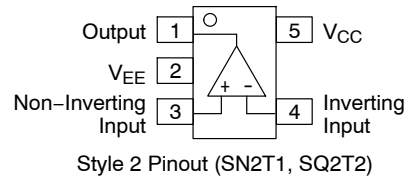
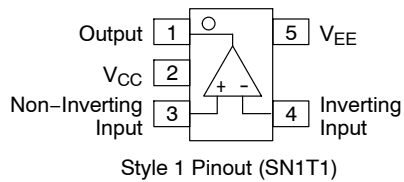


Figure 1. SOT-23-5 (NCS2200, NCS2202), SC70-5 (NCS2200, NCS2202)

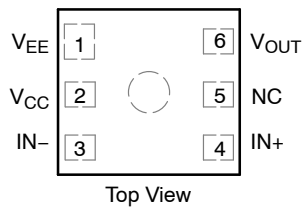


Figure 2. DFN 2x2.2 (NCS2200)

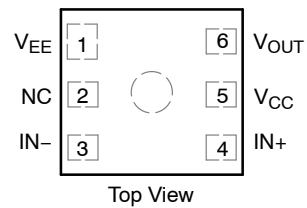


Figure 3. UDFN 1.2x1.0 (NCS2200A)

NCS2200, NCS2200A, NCV2200

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage Range (V_{CC} to V_{EE})	V_S	6.0	V
Non-inverting/Inverting Input to V_{EE}	–	–0.2 to ($V_{CC} + 0.2$)	V
Operating Junction Temperature	T_J	150	°C
Operating Ambient Temperature Range NCS2200, NCS2202, NCS2200A NCV2200, NCV2202	T_A	–40 to +105 –40 to +125	°C
Storage Temperature Range	T_{stg}	–65 to +150	°C
Output Short Circuit Duration Time (Note 1)	t_S	Indefinite	s
ESD Tolerance (Note 2) NCS2200 Human Body Model Machine Model NCS2202 Human Body Model Machine Model NCS2200A Human Body Model Machine Model	–	 2000 200 1000 200 1900 200	V
Thermal Resistance, Junction-to-Ambient TSOP–5 DFN (Note 3) SC70–5 UDFN	$R_{\theta JA}$	 238 215 283 350	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. The maximum package power dissipation limit must not be exceeded.

$$P_D = \frac{T_{J(max)} - T_A}{R_{\theta JA}}$$

2. ESD data available upon request.
3. For more information, refer to application note, AND8080/D.

NCS2200, NCS2200A, NCV2200

ELECTRICAL CHARACTERISTICS (For all values $V_{CC} = 0.85\text{ V}$ to 6.0 V , $V_{EE} = 0\text{ V}$, $T_A = 25^\circ\text{C}$, unless otherwise noted.) (Note 4)

Characteristics	Symbol	NCS2200 Series			Unit
		Min	Typ	Max	
Input Hysteresis $T_A = 25^\circ\text{C}$	V_{HYS}	2.0	8.0	20	mV
Input Offset Voltage $V_{CC} = 0.85\text{ V}$ $T_A = 25^\circ\text{C}$ $T_A = T_{Low}$ to T_{High} (Note 5) $V_{CC} = 3.0\text{ V}$ $T_A = 25^\circ\text{C}$ $T_A = T_{Low}$ to T_{High} $V_{CC} = 6.0\text{ V}$ $T_A = 25^\circ\text{C}$ $T_A = T_{Low}$ to T_{High}	V_{IO}	-10 -12 -6.0 -8.0 -5.0 -7.0	0.5 - 0.5 - 0.5 -	+10 +12 +6.0 +8.0 +5.0 +7.0	mV
Common Mode Voltage Range	V_{CM}	-	V_{EE} to V_{CC}	-	V
Output Leakage Current (NCS2202) $V_{CC} = 6.0\text{ V}$	I_{LEAK}	-	3.3	-	nA
Output Short-Circuit Sourcing or Sinking ($V_{out} = \text{GND}$)	I_{SC}	-	70	-	mA
Common Mode Rejection Ratio $V_{CM} = V_{CC}$	CMRR	53	65	-	dB
Input Bias Current	I_{IB}	-	1.0	-	pA
Power Supply Rejection Ratio $\Delta V_S = 2.575\text{ V}$	PSRR	45	55	-	dB
Supply Current $V_{CC} = 0.85\text{ V}$ $T_A = 25^\circ\text{C}$ $T_A = T_{Low}$ to T_{High} (Note 5) $V_{CC} = 3.0\text{ V}$ $T_A = 25^\circ\text{C}$ $T_A = T_{Low}$ to T_{High} $V_{CC} = 6.0\text{ V}$ $T_A = 25^\circ\text{C}$ $T_A = T_{Low}$ to T_{High}	I_{CC}	- - -	10 - 10 - 10 -	15 17 15 17 15 17	μA
Output Voltage High (NCS2200) $V_{CC} = 0.85\text{ V}$, $I_{source} = 0.5\text{ mA}$ $T_A = 25^\circ\text{C}$ $T_A = T_{Low}$ to T_{High} (Note 5) $V_{CC} = 3.0\text{ V}$, $I_{source} = 3.0\text{ mA}$ $T_A = 25^\circ\text{C}$ $T_A = T_{Low}$ to T_{High} $V_{CC} = 6.0\text{ V}$, $I_{source} = 5.0\text{ mA}$ $T_A = 25^\circ\text{C}$ $T_A = T_{Low}$ to T_{High}	V_{OH}	$V_{CC} - 0.2$ $V_{CC} - 0.225$ $V_{CC} - 0.2$ $V_{CC} - 0.25$ $V_{CC} - 0.2$ $V_{CC} - 0.25$	$V_{CC} - 0.10$ - $V_{CC} - 0.12$ - $V_{CC} - 0.12$ -	- - -	V
Output Voltage Low $V_{CC} = 0.85\text{ V}$, $I_{sink} = 0.5\text{ mA}$ $T_A = 25^\circ\text{C}$ $T_A = T_{Low}$ to T_{High} (Note 5) $V_{CC} = 3.0\text{ V}$, $I_{sink} = 3.0\text{ mA}$ $T_A = 25^\circ\text{C}$ $T_A = T_{Low}$ to T_{High} $V_{CC} = 6.0\text{ V}$, $I_{sink} = 5.0\text{ mA}$ $T_A = 25^\circ\text{C}$ $T_A = T_{Low}$ to T_{High}	V_{OL}	- - -	$V_{EE} + 0.10$ - $V_{EE} + 0.12$ - $V_{EE} + 0.12$ -	$V_{EE} + 0.2$ $V_{EE} + 0.225$ $V_{EE} + 0.2$ $V_{EE} + 0.25$ $V_{EE} + 0.2$ $V_{EE} + 0.25$	V
Propagation Delay 20 mV Overdrive, $C_L = 15\text{ pF}$	t_{PHL} t_{PLH}	- -	700 1100	- -	ns
Output Fall Time $V_{CC} = 6.0\text{ V}$, $C_L = 50\text{ pF}$	t_{FALL}	-	20	-	ns
Output Rise Time $V_{CC} = 6.0\text{ V}$, $C_L = 50\text{ pF}$	t_{RISE}	-	16	-	ns
Powerup Time	t_{PU}	-	35	-	μs

4. The limits over the extended temperature range are guaranteed by design only.

5. NCS2200, NCS2202: $T_{Low} = -40^\circ\text{C}$, $T_{High} = +105^\circ\text{C}$; NCV2200, NCV2202: $T_{Low} = -40^\circ\text{C}$, $T_{High} = +125^\circ\text{C}$

NCS2200, NCS2200A, NCV2200

ELECTRICAL CHARACTERISTICS (For all values $V_{CC} = 0.85\text{ V}$ to 6.0 V , $V_{EE} = 0\text{ V}$, $T_A = 25^\circ\text{C}$, unless otherwise noted.) (Note 6)

Characteristics	Symbol	NCS2200A			Unit
		Min	Typ	Max	
Input Hysteresis $T_A = 25^\circ\text{C}$	V_{HYS}	2.0	4.5	20	mV
Input Offset Voltage $V_{CC} = 0.85\text{ V}$ $T_A = 25^\circ\text{C}$ $T_A = -40^\circ\text{C}$ to 105°C $V_{CC} = 3.0\text{ V}$ $T_A = 25^\circ\text{C}$ $T_A = -40^\circ\text{C}$ to 105°C $V_{CC} = 6.0\text{ V}$ $T_A = 25^\circ\text{C}$ $T_A = -40^\circ\text{C}$ to 105°C	V_{IO}	-10 -12 -6.0 -8.0 -5.0 -7.0	0.5 - 0.5 - 0.5 -	+10 +12 +6.0 +8.0 +5.0 +7.0	mV
Common Mode Voltage Range	V_{CM}	-	V_{EE} to V_{CC}	-	V
Output Short-Circuit Sourcing or Sinking ($V_{out} = \text{GND}$)	I_{SC}	-	60	-	mA
Common Mode Rejection Ratio $V_{CM} = V_{CC}$	CMRR	53	70	-	dB
Input Bias Current	I_{IB}	-	1.0	-	pA
Power Supply Rejection Ratio $\Delta V_S = 2.575\text{ V}$	PSRR	45	80	-	dB
Supply Current $V_{CC} = 0.85\text{ V}$ $T_A = 25^\circ\text{C}$ $T_A = -40^\circ\text{C}$ to 105°C $V_{CC} = 3.0\text{ V}$ $T_A = 25^\circ\text{C}$ $T_A = -40^\circ\text{C}$ to 105°C $V_{CC} = 6.0\text{ V}$ $T_A = 25^\circ\text{C}$ $T_A = -40^\circ\text{C}$ to 105°C	I_{CC}	- - - -	7.5 - 8.0 - 9.0 -	15 17 15 17 15 17	μA
Output Voltage High $V_{CC} = 0.85\text{ V}$, $I_{source} = 0.5\text{ mA}$ $T_A = 25^\circ\text{C}$ $T_A = -40^\circ\text{C}$ to 105°C $V_{CC} = 3.0\text{ V}$, $I_{source} = 3.0\text{ mA}$ $T_A = 25^\circ\text{C}$ $T_A = -40^\circ\text{C}$ to 105°C $V_{CC} = 6.0\text{ V}$, $I_{source} = 5.0\text{ mA}$ $T_A = 25^\circ\text{C}$ $T_A = -40^\circ\text{C}$ to 105°C	V_{OH}	$V_{CC} - 0.25$ $V_{CC} - 0.275$ $V_{CC} - 0.3$ $V_{CC} - 0.35$ $V_{CC} - 0.3$ $V_{CC} - 0.35$	$V_{CC} - 0.10$ - $V_{CC} - 0.12$ - $V_{CC} - 0.12$ -	- - -	V
Output Voltage Low $V_{CC} = 0.85\text{ V}$, $I_{sink} = 0.5\text{ mA}$ $T_A = 25^\circ\text{C}$ $T_A = -40^\circ\text{C}$ to 105°C $V_{CC} = 3.0\text{ V}$, $I_{sink} = 3.0\text{ mA}$ $T_A = 25^\circ\text{C}$ $T_A = -40^\circ\text{C}$ to 105°C $V_{CC} = 6.0\text{ V}$, $I_{sink} = 5.0\text{ mA}$ $T_A = 25^\circ\text{C}$ $T_A = -40^\circ\text{C}$ to 105°C	V_{OL}	- - -	$V_{EE} + 0.10$ - $V_{EE} + 0.12$ - $V_{EE} + 0.12$ -	$V_{EE} + 0.25$ $V_{EE} + 0.275$ $V_{EE} + 0.3$ $V_{EE} + 0.35$ $V_{EE} + 0.3$ $V_{EE} + 0.35$	V
Propagation Delay 20 mV Overdrive, $C_L = 15\text{ pF}$	t_{PHL} t_{PLH}	- -	460 500	- -	ns
Propagation Delay 20 mV Overdrive, $C_L = 15\text{ pF}$, 2.85 V	t_{PHL} t_{PLH}	- -	410 500	- -	ns
Propagation Delay 50 mV Overdrive, $C_L = 15\text{ pF}$, 2.85 V	t_{PHL} t_{PLH}	- -	280 350	- -	ns
Propagation Delay 100 mV Overdrive, $C_L = 15\text{ pF}$, 2.85 V	t_{PHL} t_{PLH}	- -	230 300	- -	ns
Output Fall Time $V_{CC} = 6.0\text{ V}$, $C_L = 50\text{ pF}$ (Note 7)	t_{FALL}	-	20	-	ns
Output Rise Time $V_{CC} = 6.0\text{ V}$, $C_L = 50\text{ pF}$ (Note 7)	t_{RISE}	-	16	-	ns

6. The limits over the extended temperature range are guaranteed by design only.

7. Input signal: 1 kHz, squarewave signal with 10 ns edge rate.

NCS2200, NCS2200A, NCV2200

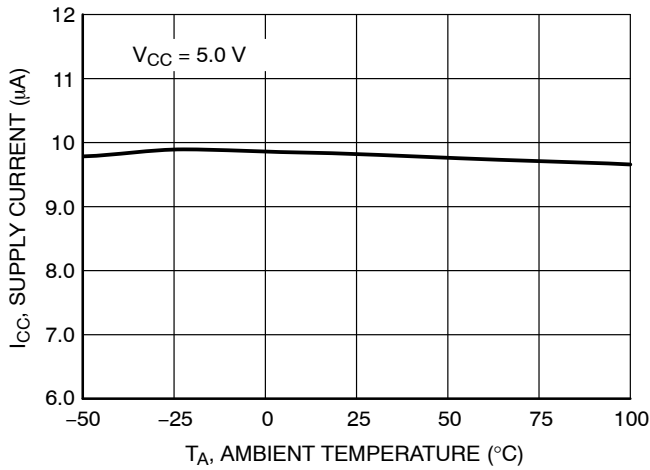


Figure 1. NCS2200 Series Supply Current versus Temperature

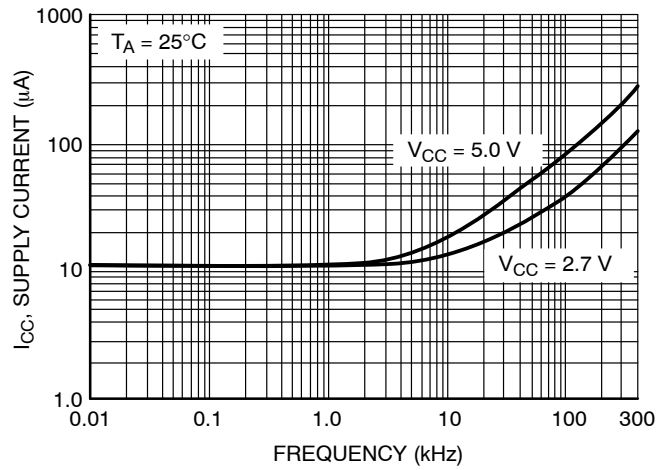


Figure 2. NCS2200 Series Supply Current versus Output Transition Frequency

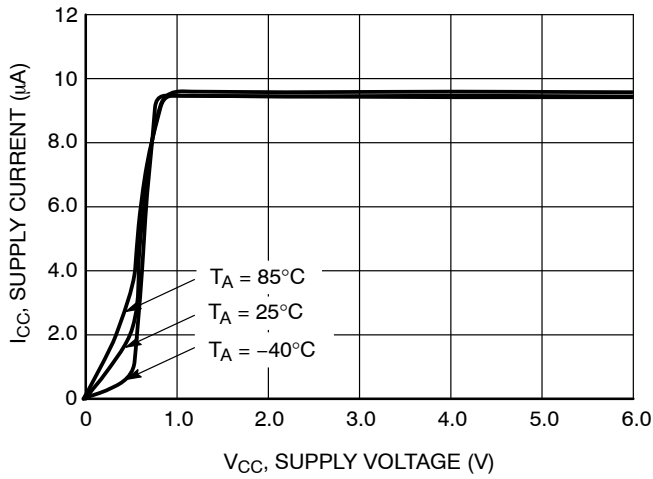


Figure 3. NCS2200 Series Supply Current versus Supply Voltage

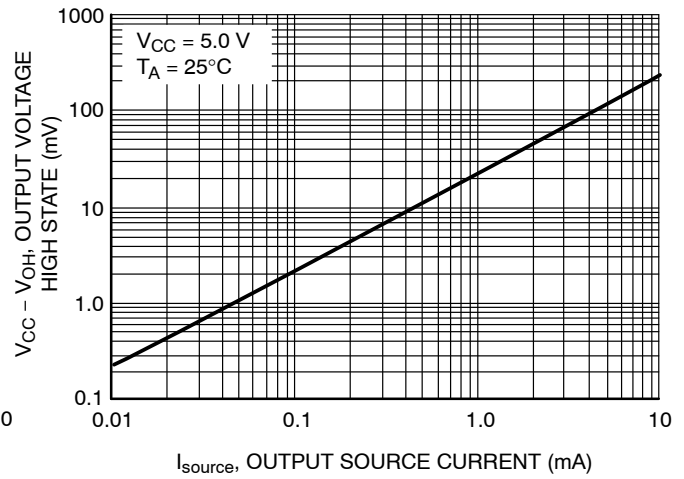


Figure 4. NCS2200 Output Voltage High State versus Output Source Current

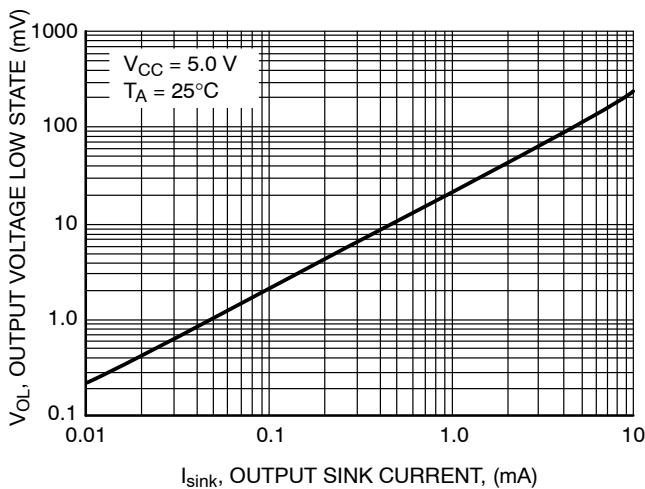


Figure 5. NCS2200 Series Output Voltage Low State versus Output Sink Current

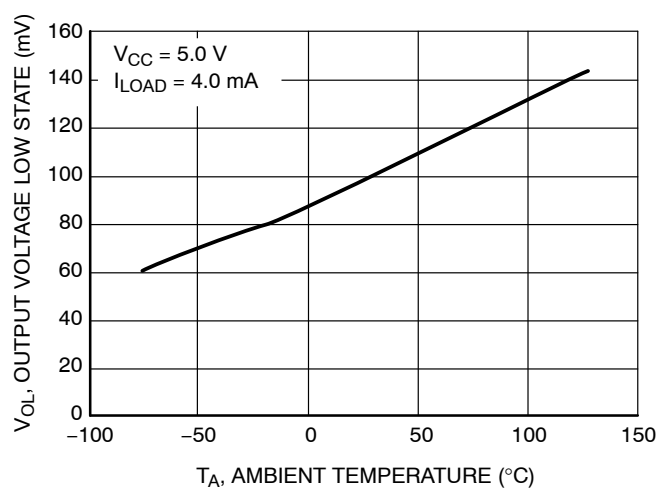


Figure 6. NCS2200 Series Output Voltage Low State versus Temperature

NCS2200, NCS2200A, NCV2200

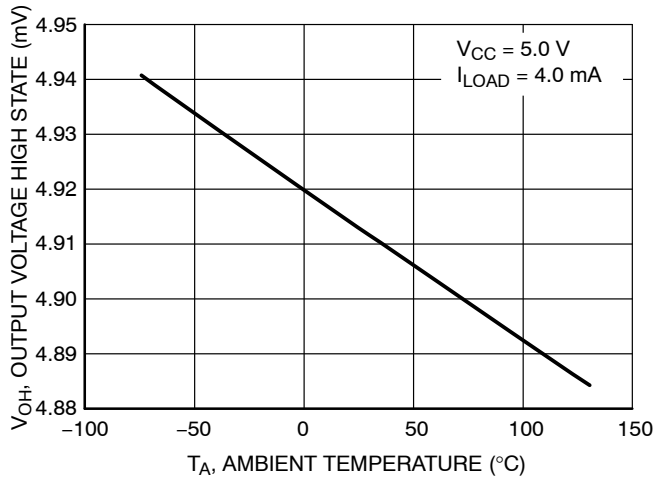


Figure 7. NCS2200 Series Output Voltage High State versus Temperature

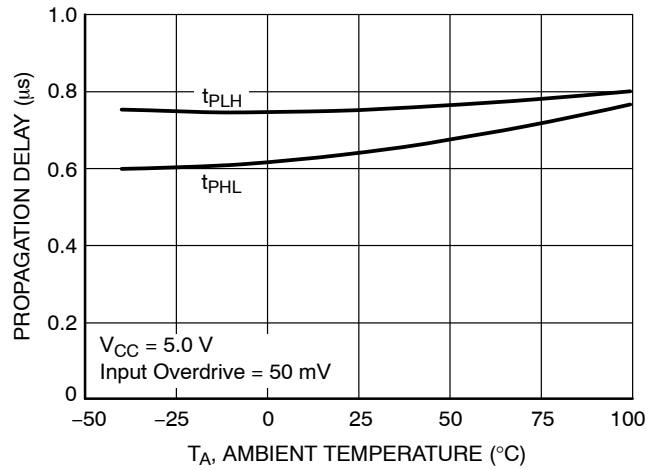


Figure 8. NCS2200 Series Propagation Delay versus Temperature

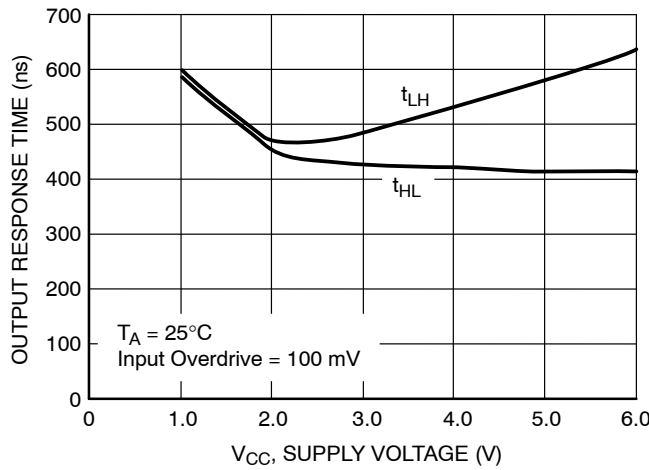


Figure 9. NCS2200 Series Output Response Time versus Supply Voltage

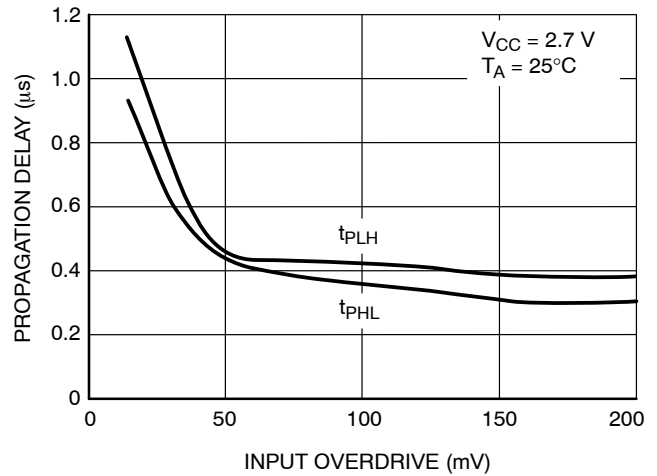


Figure 10. NCS2200 Series Propagation Delay versus Input Overdrive

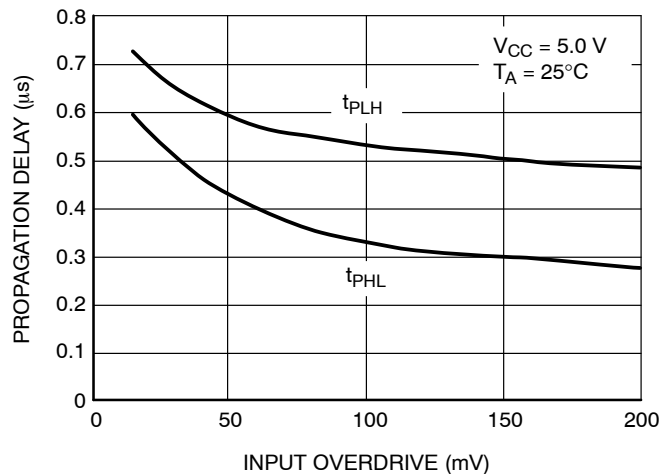


Figure 11. NCS2200 Series Propagation Delay versus Input Overdrive

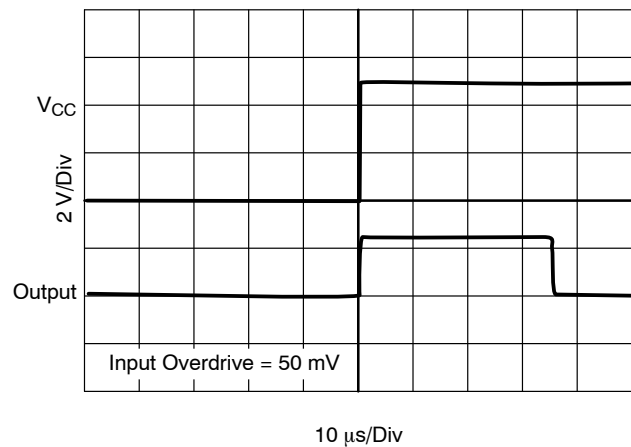


Figure 12. NCS2200 Series Powerup Delay

NCS2200, NCS2200A, NCV2200

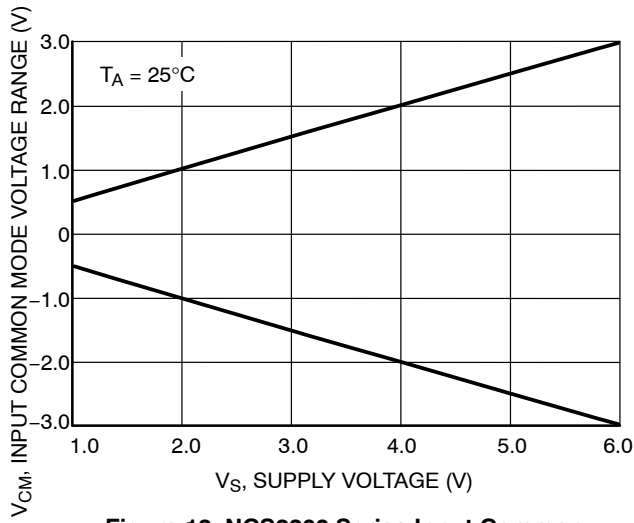


Figure 13. NCS2200 Series Input Common Mode Voltage Range versus Supply Voltage

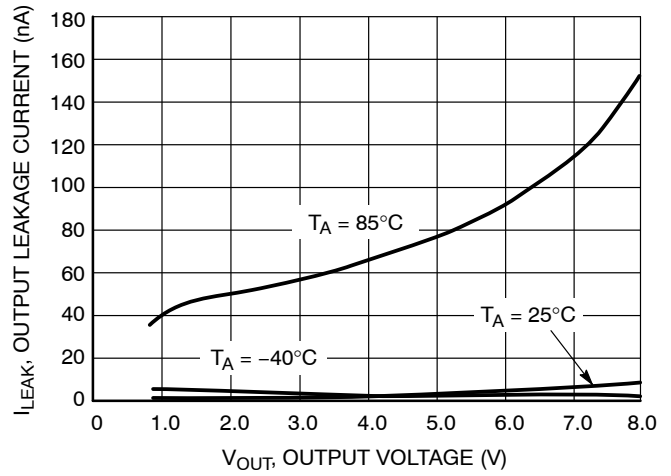


Figure 14. NCS2202 Output Leakage Current versus Output Voltage

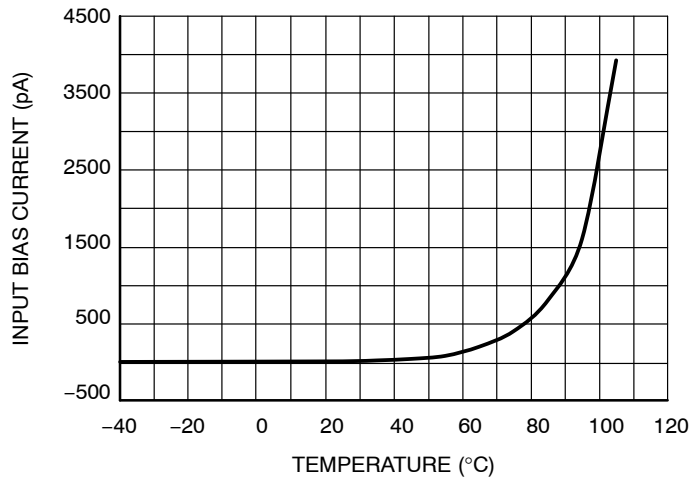


Figure 15.

OPERATING DESCRIPTION

The NCS2200 Series is an industry first sub-one volt, low power comparator family. This series is designed for rail-to-rail input and output performance. These devices consume only 10 μ A of supply current while achieving a typical propagation delay of 1.1 μ s at a 20 mV input overdrive. Figures 10 and 11 show propagation delay with various input overdrives. This comparator family is guaranteed to operate at a low voltage of 0.85 V up to 6.0 V. This is accomplished by the use of a modified analog CMOS process that implements depletion MOSFET devices. The common-mode input voltage range extends 0.1 V beyond the upper and lower rail without phase inversion or other adverse effects. This series is available in the SOT-23-5

package. Additionally, the NCS2200 device is available in the tiny DFN 2x2.2 package and the SC70-5 package. NCS2200A is available in UDFN package.

Output Stage

The NCS2200 has a complementary P and N Channel output stage that has capability of driving a rail-to-rail output swing with a load ranging up to 5.0 mA. It is designed such that shoot-through current is minimized while switching. This feature eliminates the need for bypass capacitors under most circumstances.

The NCS2202 has an open drain N-channel output stage that can be pulled up to 6.0 V (max) with an external resistor. This facilitates mixed voltage system applications.

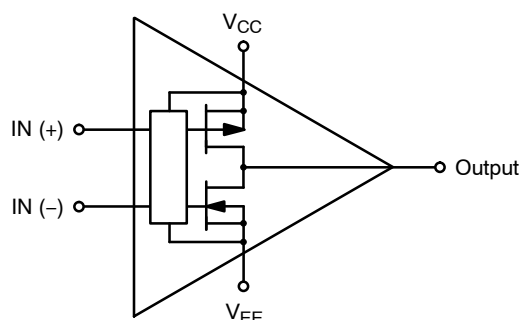


Figure 16. NCS2200SNxT1/NCS2200A Complementary Output Configuration

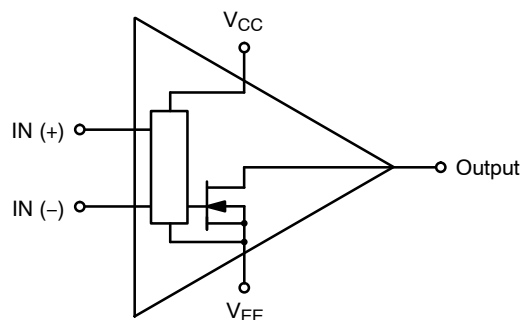
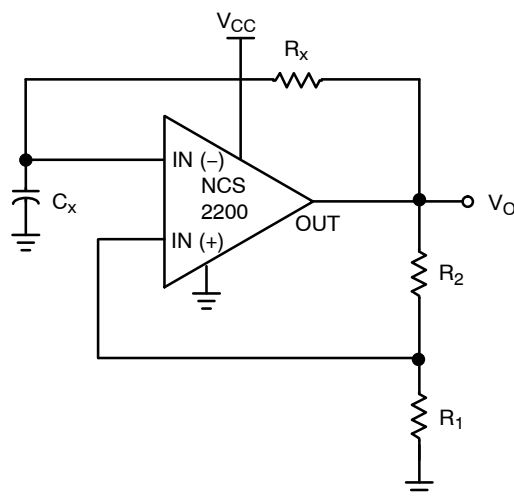


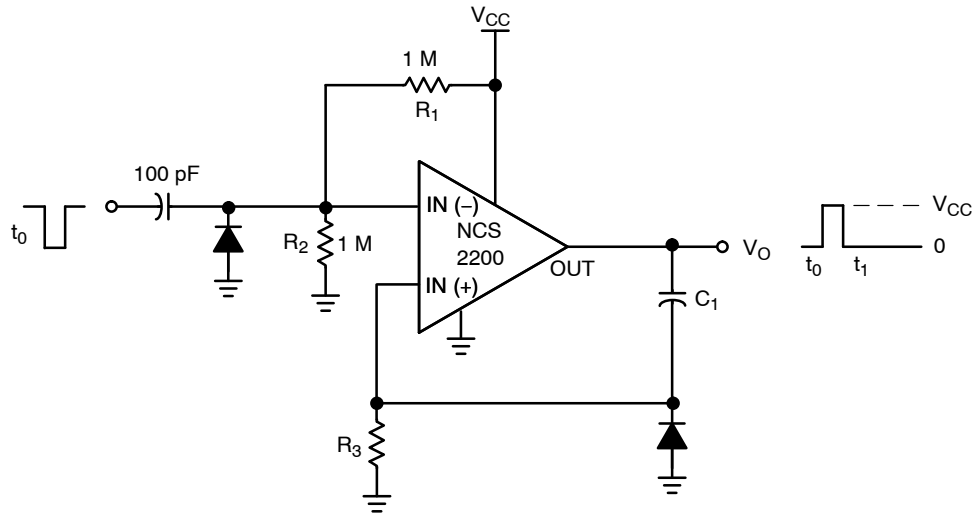
Figure 17. NCS2202SNxT1 Open Drain Output Configuration



The oscillation frequency can be programmed as follows:

$$f = \frac{1}{T} = \frac{1}{2.2 R_X C_X}$$

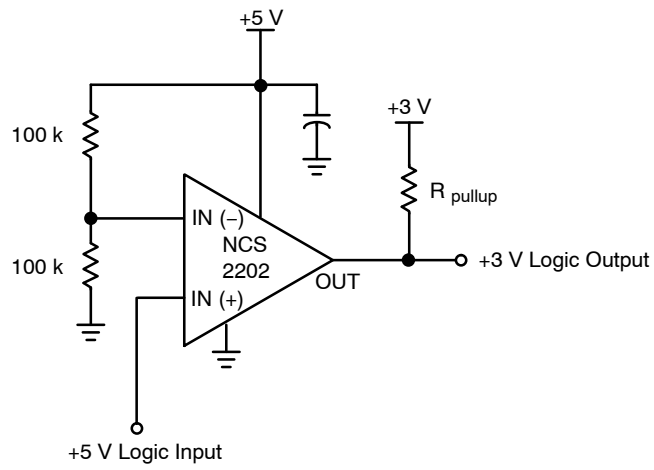
Figure 18. Schmitt Trigger Oscillator



The resistor divider R_1 and R_2 can be used to set the magnitude of the input pulse. The pulse width is set by adjusting C_1 and R_3 .

Figure 19. One-Shot Multivibrator

NCS2200, NCS2200A, NCV2200



This circuit converts 5 V logic to 3 V logic. Using the NCS2202/3 allows for full 5 V logic swing without creating overvoltage on the 3 V logic input.

Figure 20. Logic Level Translator

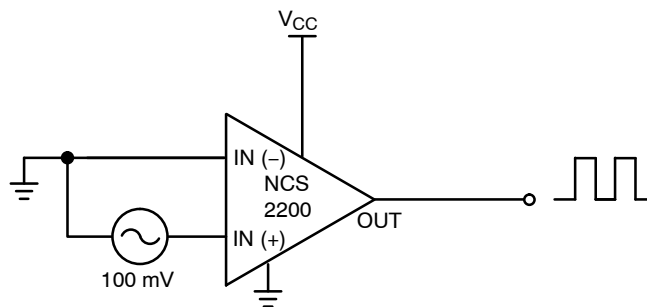


Figure 21. Zero-Crossing Detector

NCS2200, NCS2200A, NCV2200

ORDERING INFORMATION

Device	Pinout Style	Output Type	Package	Shipping†
NCS2200AMUT1G	N/A	Complementary	UDFN (Pb-Free)	3000 / Tape & Reel
NCS2200SN1T1G	1	Complementary	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCV2200SN1T1G*	1	Complementary	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCS2200SN2T1G	2	Complementary	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCV2200SN2T1G*	2	Complementary	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCS2200SQ2T2G	2	Complementary	SC70-5 (Pb-Free)	3000 / Tape & Reel
NCV2200SQ2T2G*	2	Complementary	SC70-5 (Pb-Free)	3000 / Tape & Reel
NCS2200SQLT1G	N/A	Complementary	DFN, 2x2.2 (Pb-Free)	3000 / Tape & Reel
NCS2202SN1T1G	1	Open Drain	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCS2202SN2T1G	2	Open Drain	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCV2202SN2T1G*	2	Open Drain	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCS2202SQ1T2G	1	Open Drain	SC70-5 (Pb-Free)	3000 / Tape & Reel
NCS2202SQ2T2G	2	Open Drain	SC70-5 (Pb-Free)	3000 / Tape & Reel

This device contains 93 active transistors.

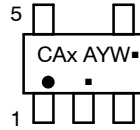
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

NCS2200, NCS2200A, NCV2200

MARKING DIAGRAMS

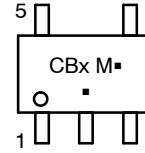
SOT-23-5 (TSOP-5) SN SUFFIX CASE 483



- x = I for NCS2200SN1T1
J for NCS2200SN2T1
M for NCS2202SN1T1
N for NCS2202SN2T1
- A = Assembly Location
- Y = Year
- W = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

SC70-5 SQ SUFFIX CASE 419A

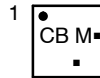


- CBx = Specific Device Code
- x = A for NCS2200SQ2T2
D for NCS2202SQ1T2G
E for NCS2202SQ2T2G
- M = Date Code*
- = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation, position, and underbar may vary depending upon manufacturing location.

DFN6 2x2.2 SQL SUFFIX CASE 488

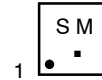


- CB = Specific Device Code
- M = Date Code*
- = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code overbar and underbar may vary depending upon manufacturing location.

UDFN6 1.2x1.0 MU SUFFIX CASE 517AA



(Top View)

- S = Specific Device Code
- M = Date Code
- = Pb-Free Package

NCS2200, NCS2200A, NCV2200

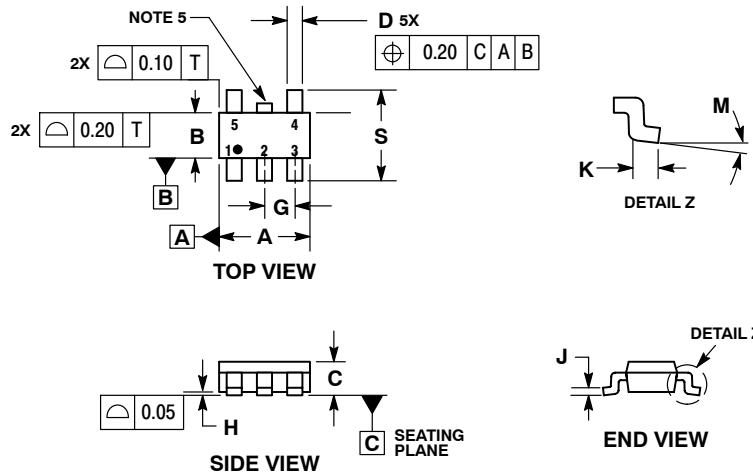
PACKAGE DIMENSIONS

SOT-23-5 / TSOP-5 / SC59-5

SN SUFFIX

CASE 483-02

ISSUE K

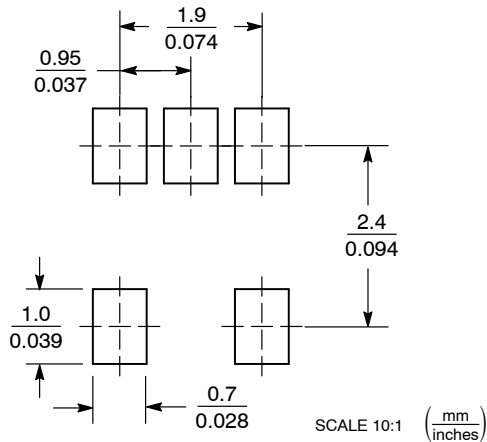


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION A.
5. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

DIM	MILLIMETERS	
	MIN	MAX
A	3.00 BSC	
B	1.50 BSC	
C	0.90	1.10
D	0.25	0.50
G	0.95 BSC	
H	0.01	0.10
J	0.10	0.26
K	0.20	0.60
M	0°	10°
S	2.50	3.00

SOLDERING FOOTPRINT*

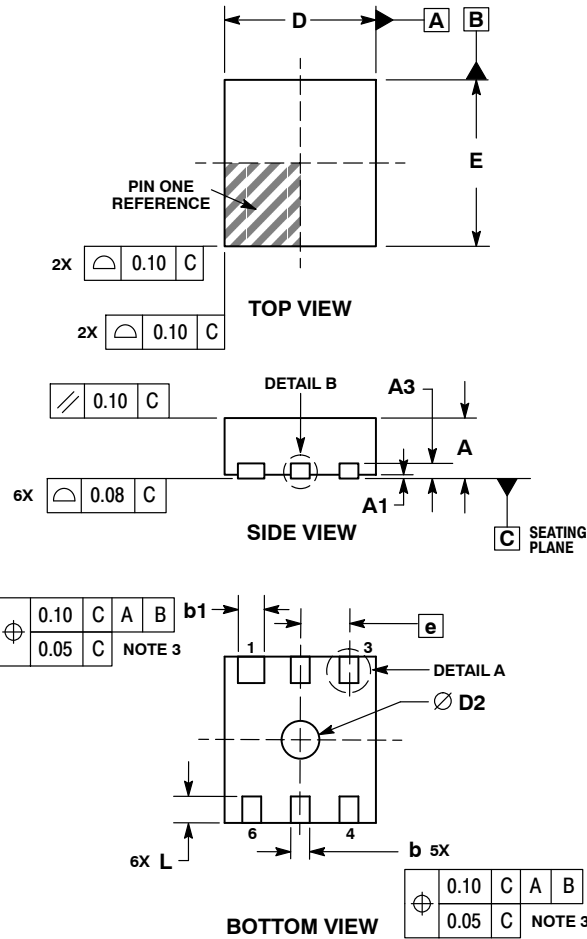


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NCS2200, NCS2200A, NCV2200

PACKAGE DIMENSIONS

DFN6, 2x2.2
SQL SUFFIX
CASE 488-03
ISSUE G

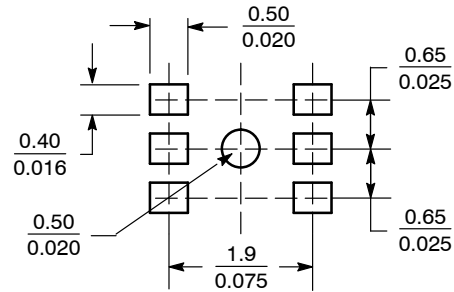


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30mm FROM TERMINAL.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
5. TERMINAL b MAY HAVE MOLD COMPOUND MATERIAL ALONG SIDE EDGE.
6. DETAILS A AND B SHOW OPTIONAL VIEWS FOR END OF TERMINAL LEAD AT EDGE OF PACKAGE AND SIDE EDGE OF PACKAGE.

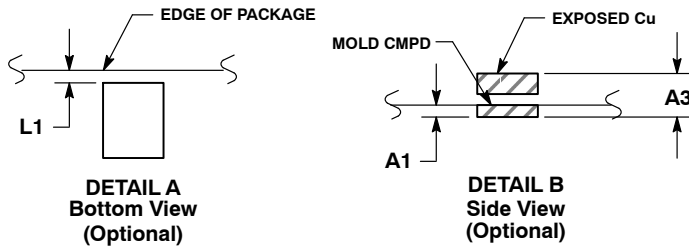
DIM	MILLIMETERS		
	MIN	NOM	MAX
A	0.80	0.90	1.00
A1	0.00	0.03	0.05
A3	0.20 REF		
b	0.20	0.25	0.30
b1	0.30	0.35	0.40
D	2.00 BSC		
D2	0.40	0.50	0.60
E	2.20 BSC		
e	0.65 BSC		
L	0.30	0.35	0.40
L1	0.00	0.05	0.10

SOLDERING FOOTPRINT*



SCALE 10:1

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



NCS2200, NCS2200A, NCV2200

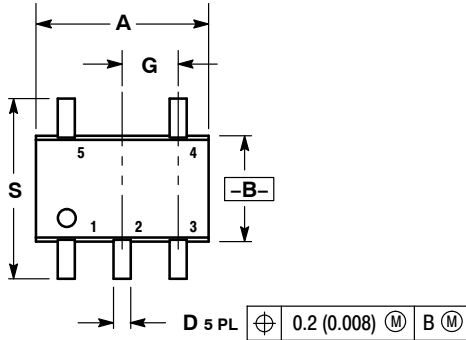
PACKAGE DIMENSIONS

SC-88A (SC-70-5/SOT-353)

SQ SUFFIX

CASE 419A-02

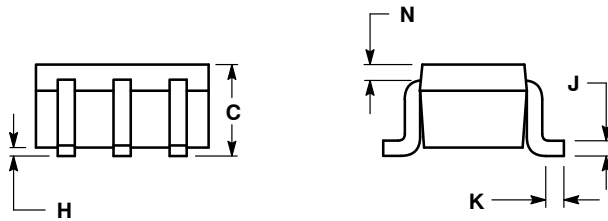
ISSUE L



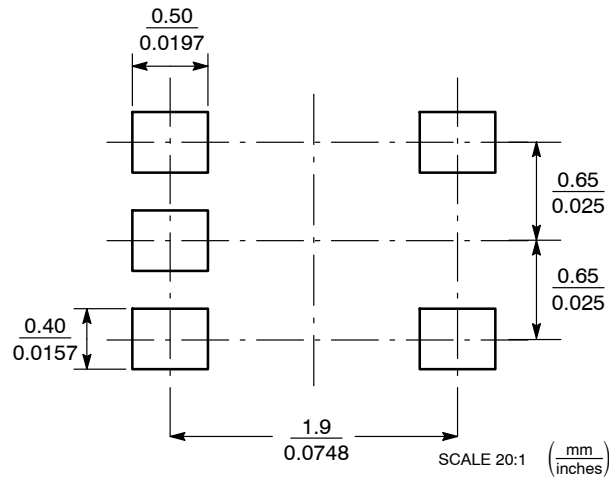
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65 BSC	
H	---	0.004	---	0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20 REF	
S	0.079	0.087	2.00	2.20



SOLDERING FOOTPRINT*

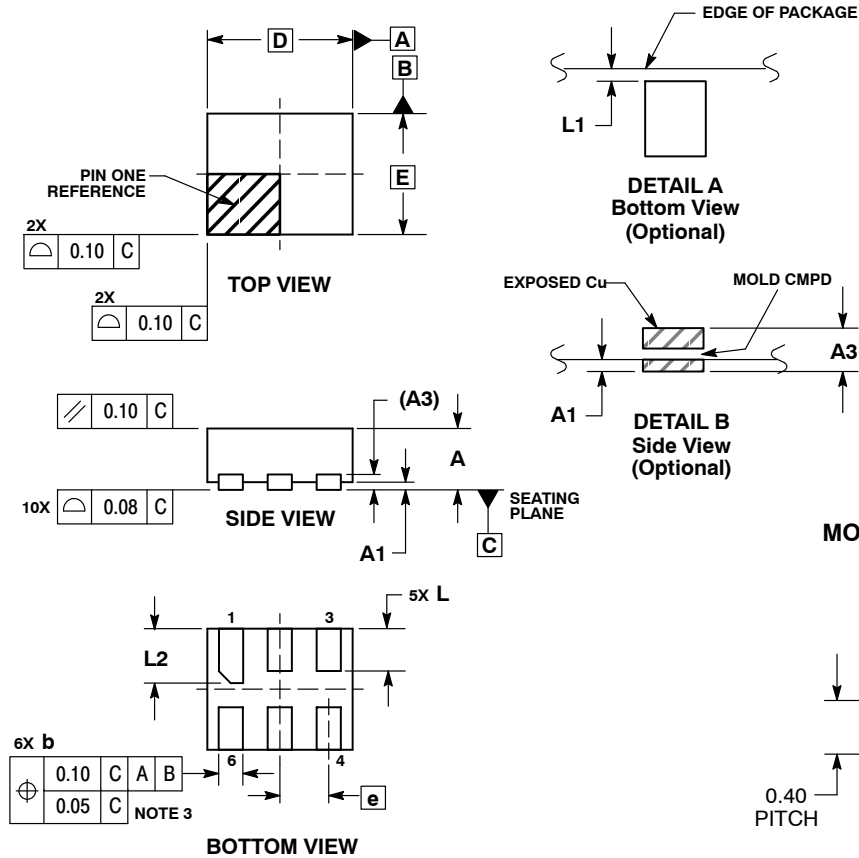


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NCS2200, NCS2200A, NCV2200

PACKAGE DIMENSIONS

UDFN6, 1.2x1.0, 0.4P
CASE 517AA
ISSUE D

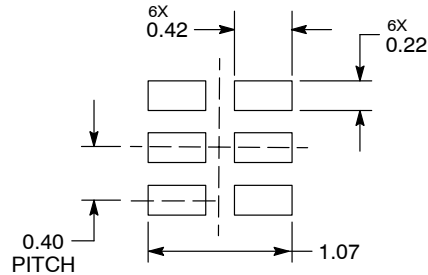


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 mm FROM TERMINAL.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

MILLIMETERS		
DIM	MIN	MAX
A	0.45	0.55
A1	0.00	0.05
A3	0.127 REF	
b	0.15	0.25
D	1.20 BSC	
E	1.00 BSC	
e	0.40 BSC	
L	0.30	0.40
L1	0.00	0.15
L2	0.40	0.50

MOUNTING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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